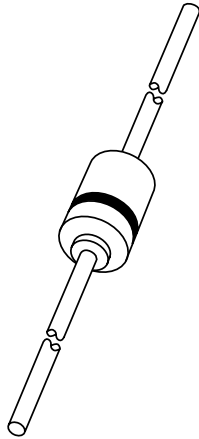


DATA SHEET



BZV85 series Voltage regulator diodes

Product data sheet
Supersedes data of 1996 Apr 26

1999 May 11

Voltage regulator diodes

BZV85 series

FEATURES

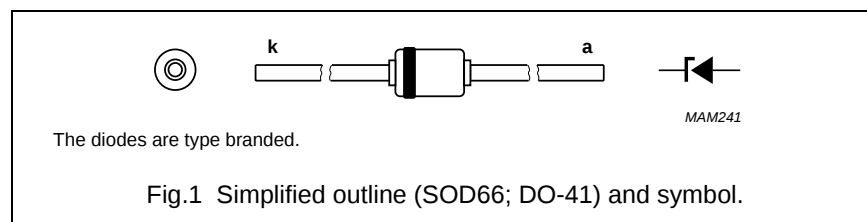
- Total power dissipation:
max. 1.3 W
- Tolerance series: approx. $\pm 5\%$
- Working voltage range:
nom. 3.6 to 75 V (E24 range)
- Non-repetitive peak reverse power
dissipation: max. 60 W.

APPLICATIONS

- Stabilization purposes.

DESCRIPTION

Medium-power voltage regulator diodes in hermetically sealed leaded glass SOD66 (DO-41) packages. The diodes are available in the normalized E24 approx. $\pm 5\%$ tolerance range. The series consists of 33 types with nominal working voltages from 3.6 to 75 V (BZV85-C3V6 to BZV85-C75).



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_F	continuous forward current		—	500	mA
I_{ZSM}	non-repetitive peak reverse current	$t_p = 100 \mu s$; square wave; $T_j = 25^\circ C$ prior to surge; see Fig.3	see Table "Per type"		
		$t_p = 10 ms$; half sinewave; $T_j = 25^\circ C$ prior to surge	see Table "Per type"		
P_{tot}	total power dissipation	$T_{amb} = 25^\circ C$; lead length 10 mm; note 1	—	1	W
		note 2	—	1.3	W
P_{ZSM}	non-repetitive peak reverse power dissipation	$t_p = 100 \mu s$; square wave; $T_j = 25^\circ C$ prior to surge	—	60	W
T_{stg}	storage temperature		-65	+200	$^\circ C$
T_j	junction temperature		—	200	$^\circ C$

Notes

1. Device mounted on a printed circuit-board with 1 cm² copper area per lead.
2. If the leads are kept at $T_{tp} = 55^\circ C$ at 4 mm from body.

ELECTRICAL CHARACTERISTICS

Total series

$T_j = 25^\circ C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V_F	forward voltage	$I_F = 50 mA$; see Fig.4	1	V

Voltage regulator diodes

BZV85 series

Per type

T_j = 25 °C unless otherwise specified.

BZV85- CXXX	WORKING VOLTAGE V _Z (V) at I _{Ztest}		DIFFERENTIAL RESISTANCE r _{dif} (Ω) at I _{Ztest}	TEMP. COEFF. S _Z (mV/K) at I _{Ztest} see Figs 5 and 6		TEST CURRENT I _{Ztest} (mA)	DIODE CAP. C _d (pF) at f = 1 MHz; V _R = 0 V	REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT I _{ZSM}	
								I _R (μA)	V _R (V)	at t _p = 100 μs; T _{amb} = 25 °C	at t _p = 10 ms; T _{amb} = 25 °C
	MIN.	MAX.	MAX.	MIN.	MAX.	MAX.	MAX.	MAX.	MAX. (A)	MAX. (mA)	
3V6	3.4	3.8	15	−3.5	−1.0	60	450	50	1.0	8.0	2000
3V9	3.7	4.1	15	−3.5	−1.0	60	450	10	1.0	8.0	1950
4V3	4.0	4.6	13	−2.7	0	50	450	5	1.0	8.0	1850
4V7	4.4	5.0	13	−2.0	+0.7	45	300	3	1.0	8.0	1800
5V1	4.8	5.4	10	−0.5	+2.2	45	300	3	2.0	8.0	1750
5V6	5.2	6.0	7	0	2.7	45	300	2	2.0	8.0	1700
6V2	5.8	6.6	4	0.6	3.6	35	200	2	3.0	7.0	1620
6V8	6.4	7.2	3.5	1.3	4.3	35	200	2	4.0	7.0	1550
7V5	7.0	7.9	3	2.5	5.5	35	150	1	4.5	5.0	1500
8V2	7.7	8.7	5	3.1	6.1	25	150	0.7	5.0	5.0	1400
9V1	8.5	9.6	5	3.8	7.2	25	150	0.7	6.5	4.0	1340
10	9.4	10.6	8	4.7	8.5	25	90	0.2	7.0	4.0	1200
11	10.4	11.6	10	5.3	9.3	20	85	0.2	7.7	3.0	1100
12	11.4	12.7	10	6.3	10.8	20	85	0.2	8.4	3.0	1000
13	12.4	14.1	10	7.4	12.0	20	80	0.2	9.1	3.0	900
15	13.8	15.6	15	8.9	13.6	15	75	0.05	10.5	2.5	760
16	15.3	17.1	15	10.7	15.4	15	75	0.05	11.0	1.75	700
18	16.8	19.1	20	11.8	17.1	15	70	0.05	12.5	1.75	600
20	18.8	21.2	24	13.6	19.1	10	60	0.05	14.0	1.75	540
22	20.8	23.3	25	16.6	22.1	10	60	0.05	15.5	1.5	500
24	22.8	25.6	30	18.3	24.3	10	55	0.05	17	1.5	450
27	25.1	28.9	40	20.1	27.5	8	50	0.05	19	1.2	400
30	28.0	32.0	45	22.4	32.0	8	50	0.05	21	1.2	380

Voltage regulator diodes

BZV85 series

BZV85- CXXX	WORKING VOLTAGE V _Z (V) at I _{Ztest}		DIFFERENTIAL RESISTANCE r _{dif} (Ω) at I _{Ztest}	TEMP. COEFF. S _Z (mV/K) at I _{Ztest} see Figs 5 and 6		TEST CURRENT I _{Ztest} (mA)	DIODE CAP. C _d (pF) at f = 1 MHz; V _R = 0 V	REVERSE CURRENT at REVERSE VOLTAGE		NON-REPETITIVE PEAK REVERSE CURRENT I _{ZSM}	
	MIN.	MAX.	MAX.	MIN.	MAX.			I _R (μA)	V _R (V)	at t _p = 100 μs; T _{amb} = 25 °C	at t _p = 10 ms; T _{amb} = 25 °C
							MAX.	MAX.		MAX. (A)	MAX. (mA)
33	31.0	35.0	45	24.8	35.0	8	45	0.05	23	1.0	350
36	34.0	38.0	50	27.2	39.9	8	45	0.05	25	0.9	320
39	37.0	41.0	60	29.6	43.0	6	45	0.05	27	0.8	296
43	40.0	46.0	75	34.0	48.3	6	40	0.05	30	0.7	270
47	44.0	50.0	100	37.4	52.5	4	40	0.05	33	0.6	246
51	48.0	54.0	125	40.8	56.5	4	40	0.05	36	0.5	226
56	52.0	60.0	150	46.8	63.0	4	40	0.05	39	0.4	208
62	58.0	66.0	175	52.2	72.5	4	35	0.05	43	0.4	186
68	64.0	72.0	200	60.5	81.0	4	35	0.05	48	0.35	171
75	70.0	80.0	225	66.5	88.0	4	35	0.05	53	0.3	161

Voltage regulator diodes

BZV85 series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length 4 mm; see Fig.2	110	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	lead length 10 mm; note 1	175	K/W

Note

1. Device mounted on a printed circuit-board with 1 cm² copper area per lead.

GRAPHICAL DATA

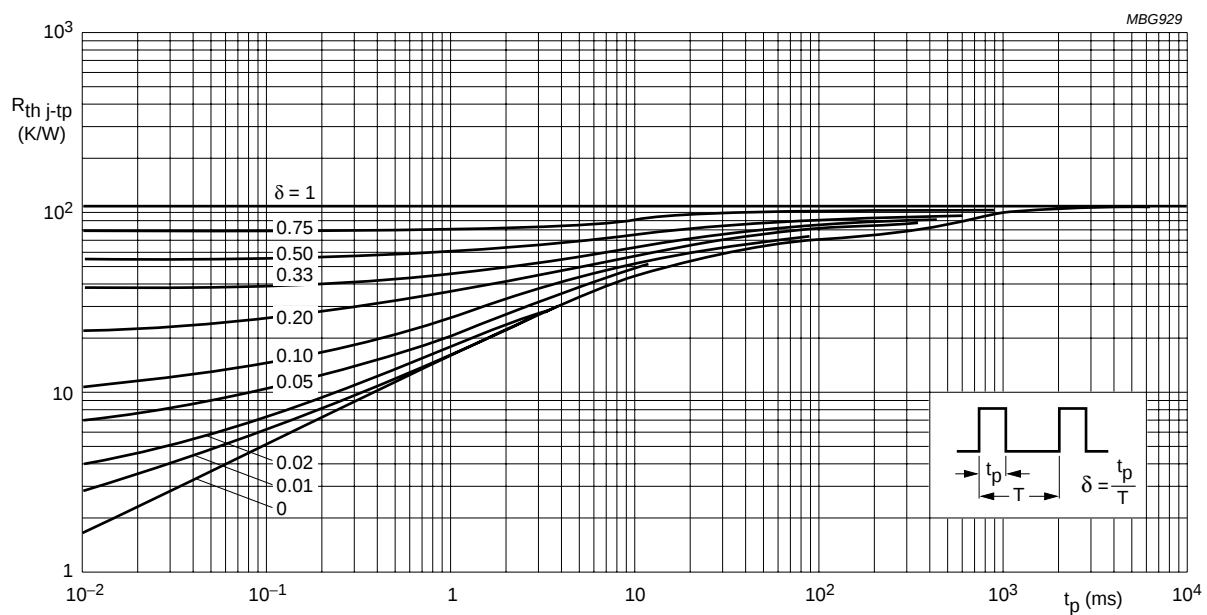
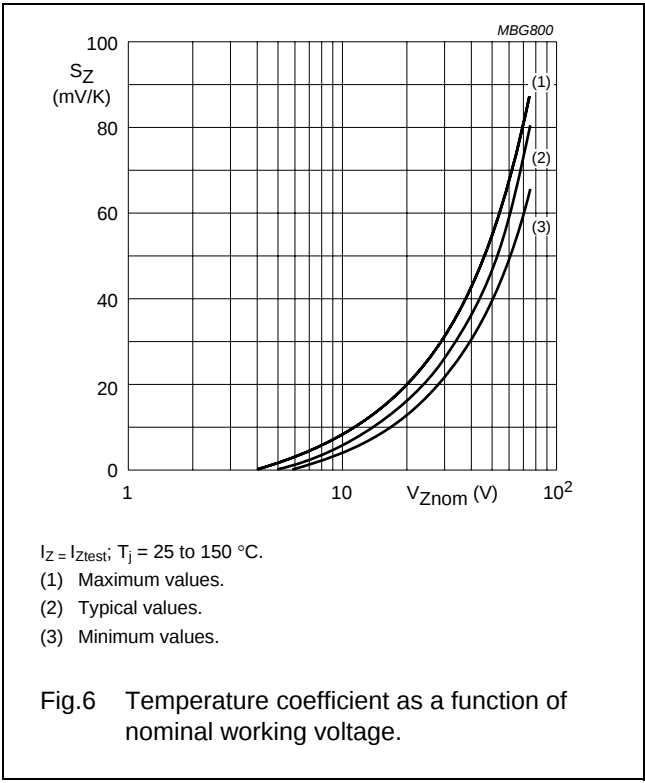
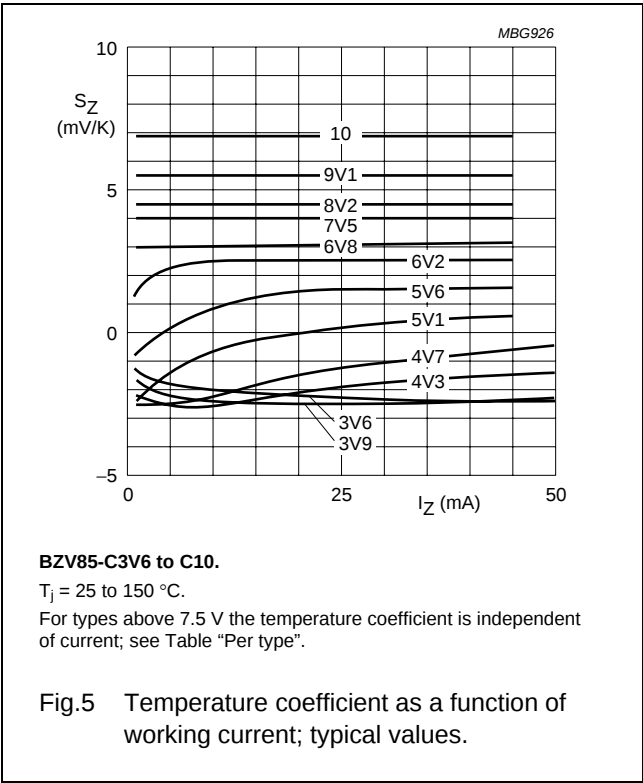
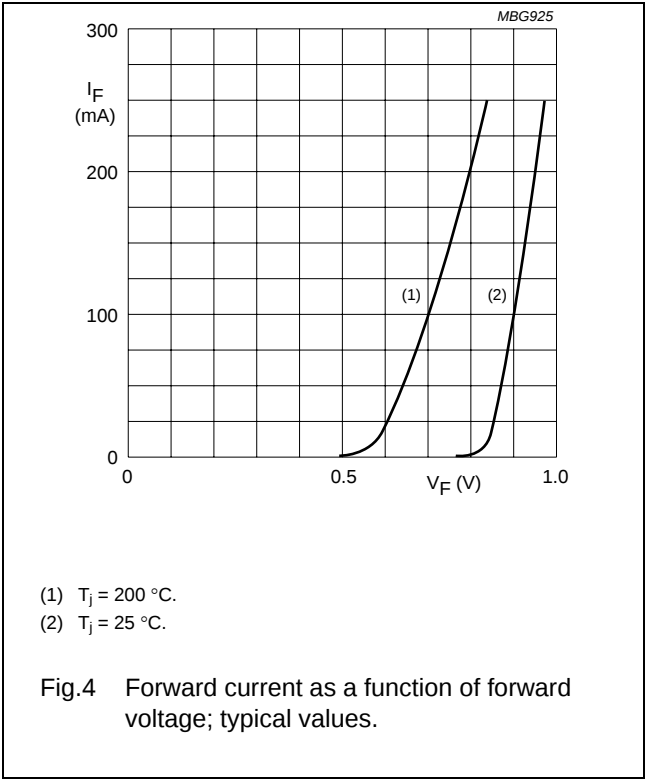
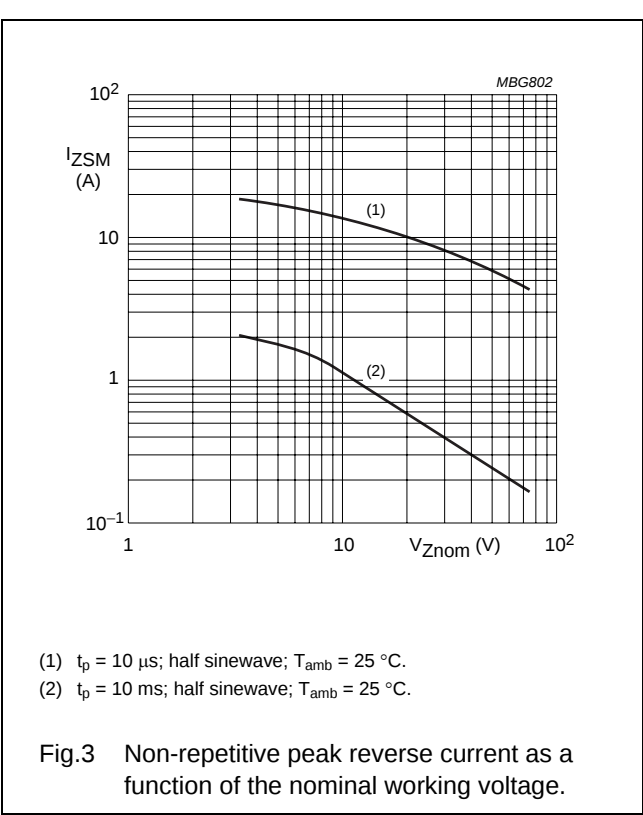


Fig.2 Thermal resistance from junction to tie-point with a lead length of 4 mm.

Voltage regulator diodes

BZV85 series



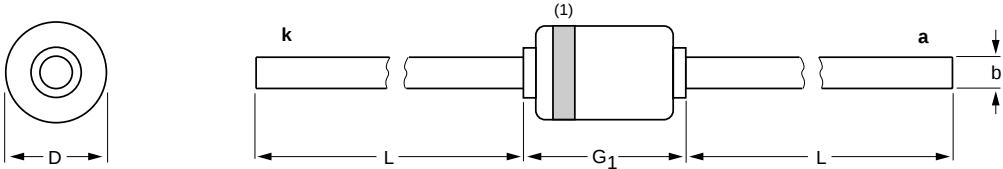
Voltage regulator diodes

BZV85 series

PACKAGE OUTLINE

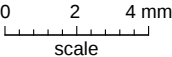
Hermetically sealed glass package; axial leaded; 2 leads

SOD66



DIMENSIONS (mm are the original dimensions)

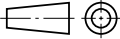
UNIT	b max.	D max.	G ₁ max.	L min.
mm	0.81	2.6	4.8	28



0 2 4 mm
scale

Note

1. The marking band indicates the cathode.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOD66		DO-41				97-06-20

Voltage regulator diodes

BZV85 series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
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Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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